**Product data sheet** 

# 1. General description

Silicon Carbide Schottky diode in a TO263 (D2PAK) plastic package, designed for high frequency switched-mode power supplies.

### 2. Features and benefits

- · Highly stable switching performance
- High forward surge capability I<sub>FSM</sub>
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

## 3. Applications

- Power factor correction
- Telecom/Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED/OLED TV
- Motor Drives

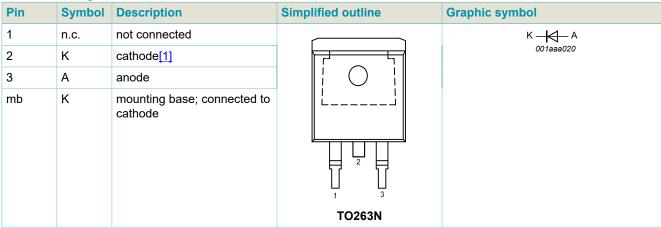
### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$V_{RRM}$	repetitive peak reverse voltage			-	-	650	V	
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 136 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4		-	-	4	Α	
Tj	junction temperature			-	-	175	°C	
Static characteristics								
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.5	1.7	V	
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.8	2.1	٧	
Dynamic characteristics								
Q <sub>r</sub>	recovered charge	$I_F = 4 \text{ A}$ ; $dI_F/dt = 500 \text{ A/}\mu\text{s}$ ; $V_R = 400 \text{ V}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7		-	7	-	nC	

# 5. Pinning information

**Table 2. Pinning information** 



<sup>[1]</sup> It is not possible to connect to pin 2 of the TO263 package.

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package					
	Name	Description	Version			
NXPSC04650B	-	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	TO263N			

# 7. Limiting values

Table 4. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	650	V
$V_{RWM}$	crest working reverse voltage		-	650	V
$V_R$	reverse voltage	DC	-	650	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 136 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4	-	4	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 µs; square-wave pulse	-	8	А
I <sub>FSM</sub>	non-repetitive peak	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse	-	24	Α
	forward current	$t_p$ = 10 $\mu$ s; $T_{j(init)}$ = 25 °C; square-wave pulse	-	235	Α
T <sub>stg</sub>	storage temperature		-55	175	°C
T <sub>j</sub>	junction temperature		-	175	°C

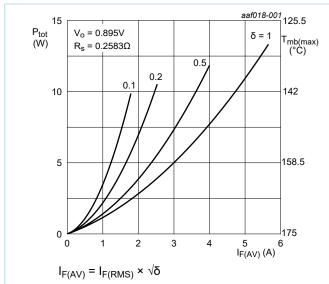


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

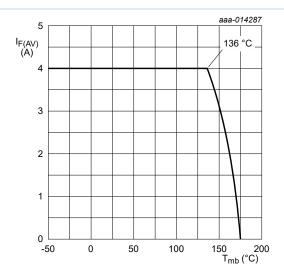


Fig. 2. Forward current as a function of mounting base temperature; maximum values

WeEn Semiconductors NXPSC04650B

### Silicon Carbide Diode

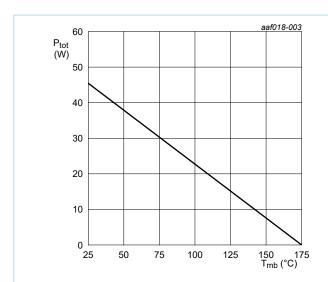


Fig. 3. Total power dissipation as a function of mounting base temperature

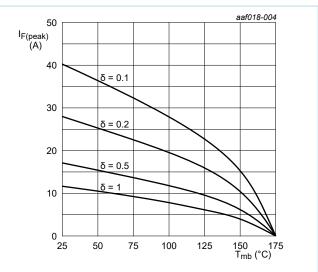


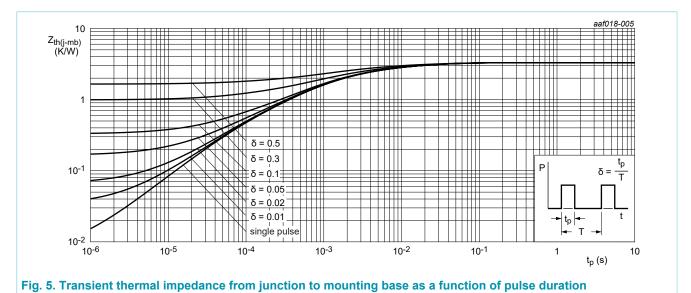
Fig. 4. Current derating as a function of mounting base temperature

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### 8. Thermal characteristics

**Table 5. Thermal characteristics** 

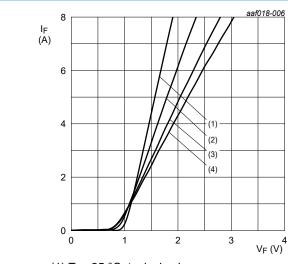
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	-	3.3	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	Device mounted on an FR4 Printed- Circuit Board (PCB)	-	50	-	K/W

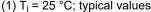


### 9. Characteristics

### **Table 6. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.5	1.7	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.8	2.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C		-	-	170	μΑ
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 150 °C		-	-	550	μΑ
Dynamic cl	haracteristics						
Q <sub>r</sub>	recovered charge	$I_F = 4 \text{ A}$ ; $dI_F/dt = 500 \text{ A/}\mu\text{s}$ ; $V_R = 400 \text{ V}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7		-	7	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C		-	130	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C		-	16	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	13	-	pF





(1)  $T_j$  = 25 °C; typical values (2)  $T_j$  = 100 °C; typical values (3)  $T_j$  = 150 °C; typical values (4)  $T_j$  = 175 °C; typical values



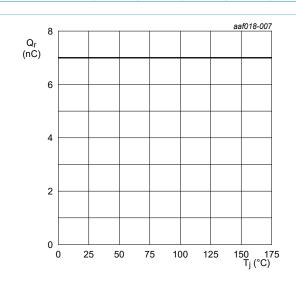
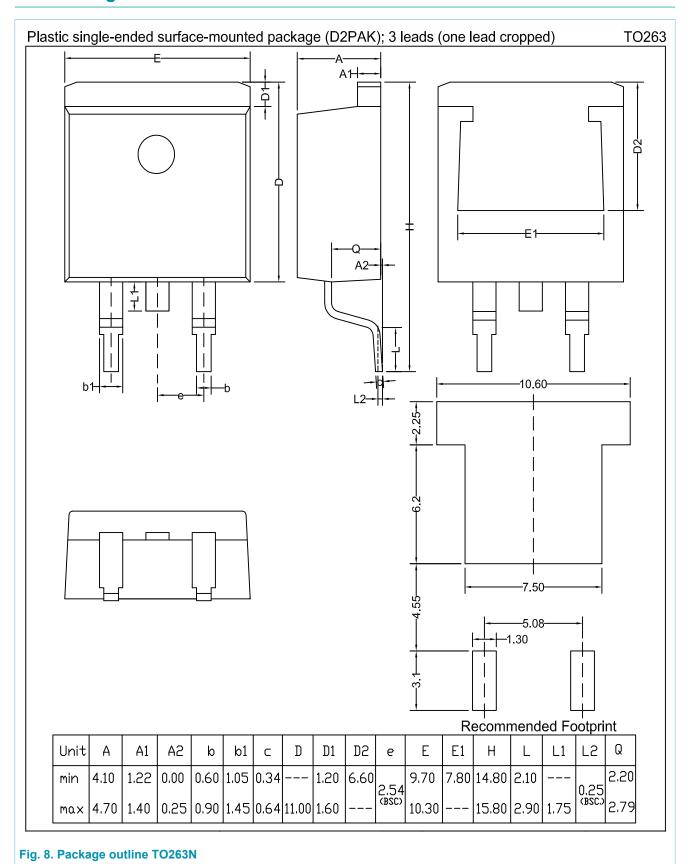


Fig. 7. Recovered charge as a function of junction temperature

### 10. Package outline



# 11. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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